



高速光耦
High Speed Photo
Coupler

ATW720

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

www.aotesemi.com

概述 Description

ATW720 (单通道) 是采用 SOP6 封装的 CMOS 光耦合器。光电耦合器利用最新的 CMOS IC 技术，以极低的功耗实现了卓越的性能。

The ATW720 (single-channel) is CMOS optocouplers in SOP6 package. The optocouplers utilize the latest CMOS IC technology to achieve outstanding performance with very low power consumption.

特性 Features

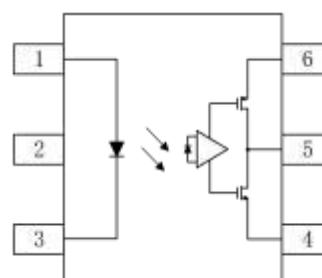
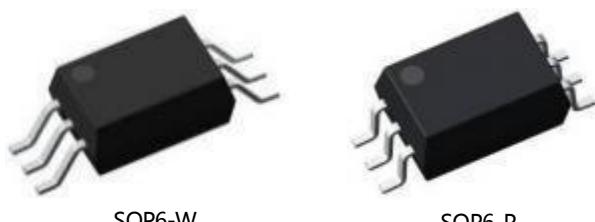
- CMOS 可兼容 : +3.3V 和 +5 V
+3.3V and +5V CMOS compatibility
- 脉冲宽度失真最大值 : 25ns
25ns max. pulse width distortion
- 传播延迟最大值 : 55ns
55 ns max. propagation delay
- 传播延迟倾斜最大值 : 40ns
40 ns max. propagation delay skew
- 高速 : 15MBd (最小)
High speed: 15 MBd min
- 共模抑制最小值 : 10 kV/μs
10 kV/μs minimum common mode rejection
- 温度范围 : -40°C ~ 105°C
-40°C to 105°C temperature range
- 无故障上电功能
Glitch-Free Power-UP Feature
- 符合安规标准 : UL 1577 , VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022
Meet Safety standard : UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022

应用 Applications

- 消除接地回路
Ground loop elimination
- 数字现场总线隔离 : RS485, RS232, CANbus
Digital field bus isolation: RS485, RS232, CANbus
- 多路数据传输
Multiplexed data transmission
- 计算机外围接口

真值表 Truthtable

| LED | VO |
|-----|----|
| OFF | H |
| ON | L |



- Pin Configuration
1. Anode
 2. NC
 3. Cathode
 4. GND
 5. VO
 6. VCC

注 : 在引脚 4 和 6 之间必须连接一个 0.1uF 的旁路电容器。

Note: 0.1uF bypass capacitor must be connected between pins 4 and 6.

产品型号命名规则 Order code

AT W720 - UN - Y-W (V) (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

① 公司代码 Company Code (AT: 奥特 Aote)

② 产品系列 Product Series (W720)

③ 框架类型 Lead Frame (Cu: 铜框架 Copper)

④ 树脂类型 Epoxy Type (H: 无卤 Halogen-free)

⑤ 封装形式 Package (S: SOP)

⑥ 器件工作温度范围 Device Operating Temperature Range (特殊范围需填或者空白 Special Range need to be filled in or left blank)

⑦ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中的 “X” 代表产品分档 : 0
“X” denotes the classification : 0
- 印字中 “Y” 代表年份 ; A(2018),B(2019),C(2020)
“Y” denotes YEAR : A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes week's number
- 印字中 “E” 代表内部代码
“E” denotes Internal code
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free



绝缘和安规信息 Insulationandsafetyrelated specifications

| 项目 Item | 符号 Symbol | 数值 Value | 单位 Unit | 备注 Remark |
|---------------------------------------|-------------------|-------------|-------------------|--|
| 爬电距离 Creepage Distance | L | >8.0 | mm | 从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body |
| 电气间隙 Clearance Distance | L | >8.0 | mm | 从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air |
| 绝缘距离 Insulation Thickness | DTI | >0.4 | mm | 发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector |
| 峰值隔离电压 Peak Isolation Voltage | V _{IORM} | 1500 | V _{peak} | DIN/EN/IEC EN60747-5-5 |
| 瞬态隔离电压 Transient isolation voltage | V _{IOTM} | 7000 | V _{peak} | DIN/EN/IEC EN60747-5-5 |
| 隔离电压 Isolation Voltage | V _{iso} | >5000 | Vrms | For 1 min |

极限参数Absolute Maximum Ratings(Ta=25°C)

| 参数 Parameter | 符号 Symbol | 最小值 Min | 最大值 Max | 单位 Unit |
|---|---|---|------------|------------|
| 电源电压 Supply Voltages | V _{DD} | 0 | 6.0 | V |
| 输出电压 Output Voltage | V _O | -0.5 | VDD+0.5 | V |
| 平均正向输入电流 Average Forward Input Current | I _F | - | 10.0 | mA |
| 平均输出电流 Average Output Current | I _O | - | 10.0 | mA |
| 隔离电压 Isolation voltage | V _{ISO} | 5000 | - | Vrms |
| 工作温度 Operating Temperature | T _{opr} | -40 | +105 | °C |
| 存储温度 Storage Temperature | T _{stg} | -55 | +125 | °C |
| 铅焊温度 Lead Solder Temperature | T _{SOL} | 260 摄氏度持续 10 秒，座位平面以下 1.6mm 260°C for 10 sec, 1.6 mm below seating plane | | |
| 焊机回流温度曲线 Solder Reflow Temperature Profile | 请参阅回流焊温度曲线部分 See Solder Reflow Temperature Profile Section | | | |

推荐工作条件 Recommended operating conditions

| 参数 Parameter | 符号 Symbol | 最小值 Min | 最大值 Max | 单位 Unit |
|-------------------------------------|--------------|------------|------------|------------|
| 电源电压 Supply Voltages | V_{DD} | 4.5 | 5.5 | V |
| | | 3 | 3.6 | V |
| 开启电流 Forward Input Current (ON) | $I_{F(ON)}$ | 3 | 10 | mA |
| 关断电压 Forward Input Voltage (OFF) | $V_{F(OFF)}$ | 0 | 1.3 | V |
| 操作温度 Operating Temperature | T_A | -40 | 105 | °C |

产品特性参数 Electro-optical characteristics ($T_A=25\text{ }^{\circ}\text{C}$, $V_{DD}=3.3\text{V}$)

| 参数 Parameter | | 符号 Symbol | 条件 Condition | 最小 Min. | 典型 Typ. | 最大 Max. | 单位 Unit |
|-----------------|---|--------------|--|-------------|---------------|------------|------------|
| 发射端 Input | 正向电压 Forward Voltage | V_F | $I_F = 6\text{mA}$ | 1 | 1.3 | 1.8 | V |
| | 反向击穿电压 Reverse Breakdown Voltage | B_{VR} | $I_R = 10\mu\text{A}$ | 5.0 | - | - | V |
| 接收端 Output | 逻辑高输出电压 Logic High Output Voltage | V_{OH} | $I_F = 0, I_O = -4\text{ mA}, V_{DD} = 3.3\text{V}$ | $V_{DD} -1$ | $V_{DD} -0.3$ | - | V |
| | | | $I_F = 0, I_O = -4\text{ mA}, V_{DD} = 5\text{V}$ | $V_{DD} -1$ | $V_{DD} -0.2$ | - | V |
| | 逻辑低输出电压 Logic Low Output Voltage | V_{OL} | $I_F = 6\text{mA}, I_O = 4\text{mA}, V_{DD} = 3.3\text{V}$ | - | 0.2 | 0.8 | V |
| | | | $I_F = 6\text{mA}, I_O = 4\text{mA}, V_{DD} = 5\text{V}$ | - | 0.35 | 0.8 | V |
| | 输入阈值电流 Input Threshold Current | I_{TH} | $I_{OL} = 20\mu\text{A}$ | - | 3 | 5 | mA |
| | 逻辑低输出电源电流 Logic Low Output Supply Current | I_{DDL} | $I_F = 6\text{ mA}$ | - | 4.5 | 6.5 | mA |
| | 逻辑高输出电源电流 Logic High Output Supply Current | I_{DDH} | $I_F = 0$ | - | 4 | 6 | mA |

开关特性switching specification(Ta=25 °C, V_{DD}=3.3v)

| 参数 Parameter | 符号 Symbol | 条件 Condition | 最小 Min. | 典型 Typ. | 最大 Max | 单位 Unit |
|---|-------------------------------|--|------------|------------|-----------|------------|
| 逻辑低电平传输延迟 Propagation Delay Time to Low Output Level | t _{PHL} ¹ | I _F = 6mA, C _L = 15pF CMOS Signal Levels | - | 40 | 55 | ns |
| 逻辑高电平传输延迟 Propagation Delay Time to High Output Level | t _{PLH} ¹ | | - | 36 | 55 | |
| 脉冲宽度 Pulse Width | t _{PW} | | 66.7 | - | - | |
| 脉宽失真 Pulse Width Distortion t _{PHL} -t _{PLH} | PWD | | 0 | 4 | 25 | |
| 传播延迟偏斜 Propagation Delay Skew | t _{PSK} | | - | - | 40 | |
| 输出上升时间 Output Rise Time (10% ~90%) | t _R | | - | 3.5 | - | |
| 输出下降时间 Output Fall Time (90% ~10%) | t _F | | - | 3.5 | - | |
| 输出高电平共模抑制 Output High Level Common Mode Transient Immunity | CMH ² | VCM =1000V I _F =0mA | 10 | 15 | - | |
| 输出低电平共模抑制 Output Low Level Common Mode Transient Immunity | CML ³ | VCM =1000V I _F =6.0mA | 10 | 15 | - | kV/μs |

注 : Note:

- 从输入脉冲上升沿的 50%V_{DD} 电平到 V_O信号下降沿的 50%V_{DD} 电平 , 测量 t_{PHL} 传播延迟。从输入脉冲下降沿的 50%V_{DD} 水平到 V_O信号上升沿的 50%V_{DD} 水平 , 测量 t_{PLH} 传播延迟。
 t_{PHL} propagation delay is measured from the 50% V_{DD} level on the rising edge of the input pulse to the 50% V_{DD} level of the falling edge of the V_O signal. t_{PLH} propagation delay is measured from the 50% V_{DD} level on the falling edge of the input pulse to the 50% V_{DD} level of the rising edge of the V_O signal.
- CMH 是共模电压上升的最大可容忍速率 , 以确保输出将保持在高逻辑状态。
 CMH is the maximum tolerable rate of rise of the common mode voltage to assure that the output will remain in a high logic state.
- CML 是共模电压的最大可容忍的下降率 , 以确保输出将保持在低逻辑状态。
 CML is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state.

典型光电特性曲线 Typical Electro-optical characteristics curves

Fig.1 Input current vs. Forward Voltage

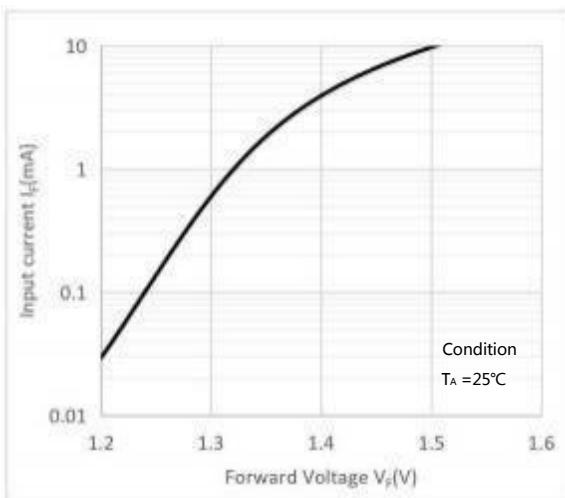


Fig.3 Logic high output supply current vs. Ambient temperature

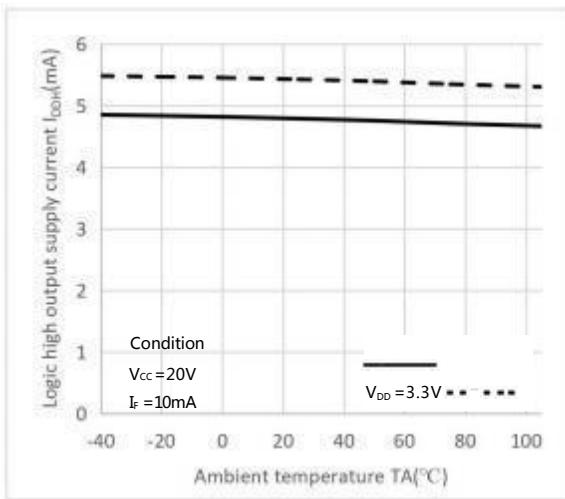


Fig.5 Propagation delay vs. Pulse input current

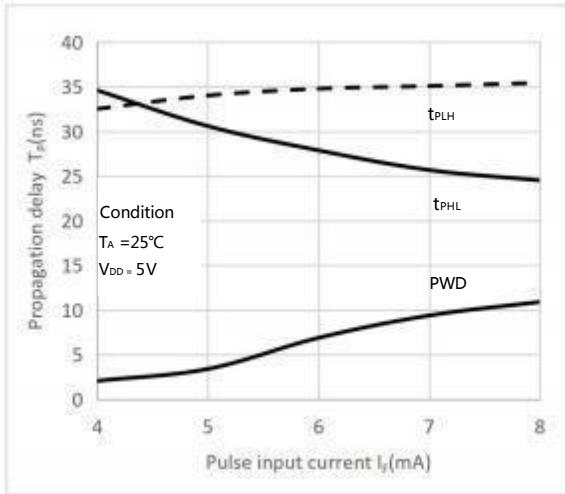


Fig.2 Input threshold current vs. Ambient temperature

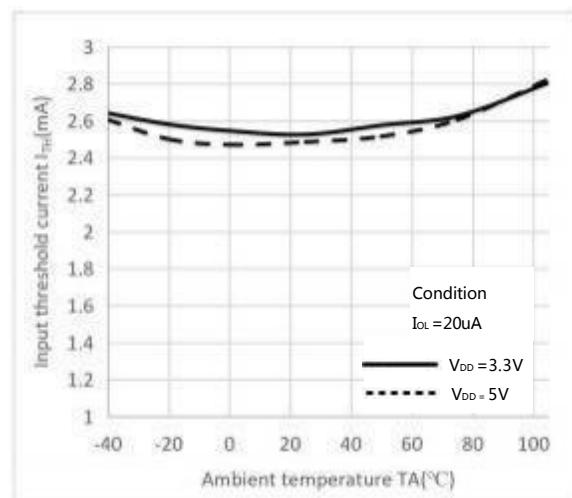


Fig.4 Logic low output supply current vs. Ambient temperature

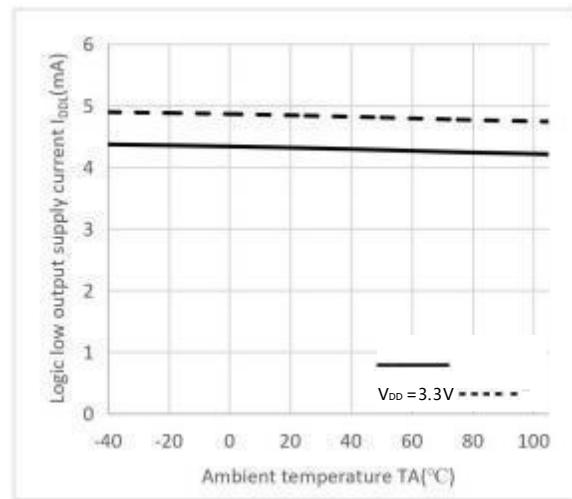


Fig.6 Propagation delay vs. Pulse input current

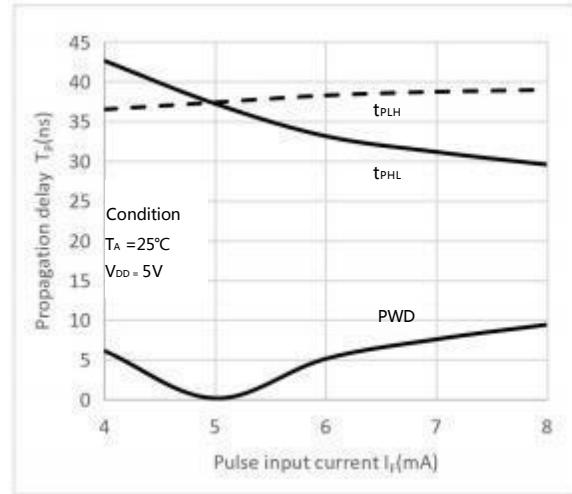


Fig.7 Forward voltage vs. Ambient temperature

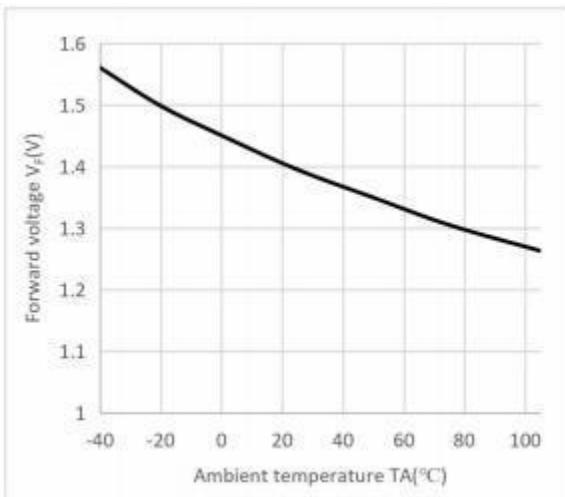


Fig.8 Propagation delay vs. Ambient temperature
(V_{DD}=5V,C_{peak}=100pF,R_{limit}=530 Ω)

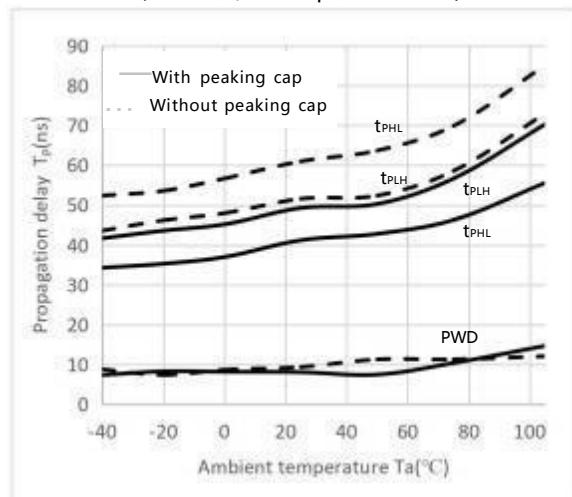
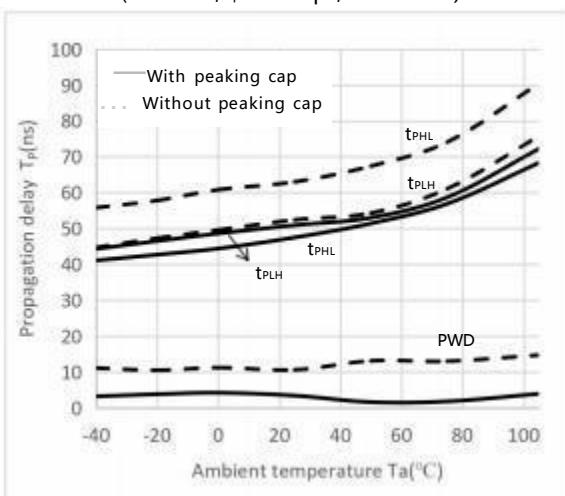
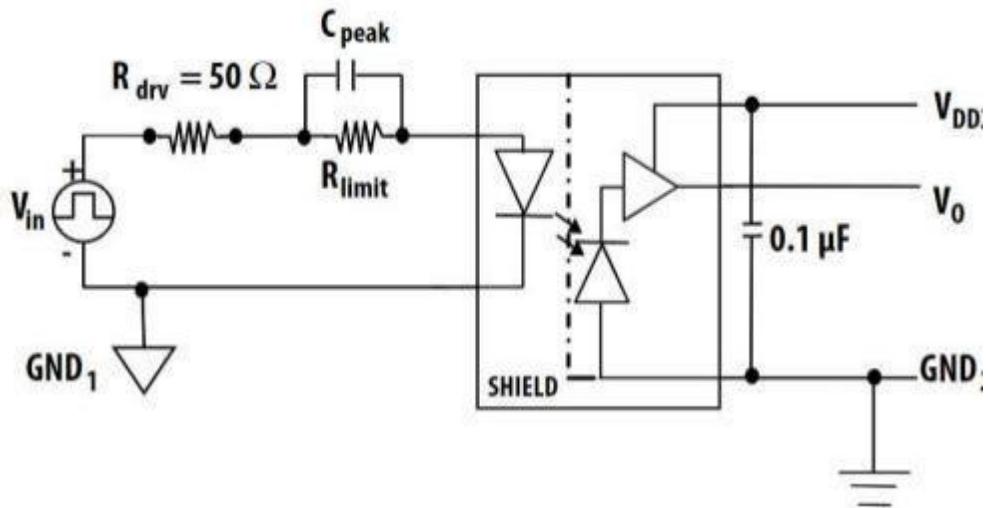


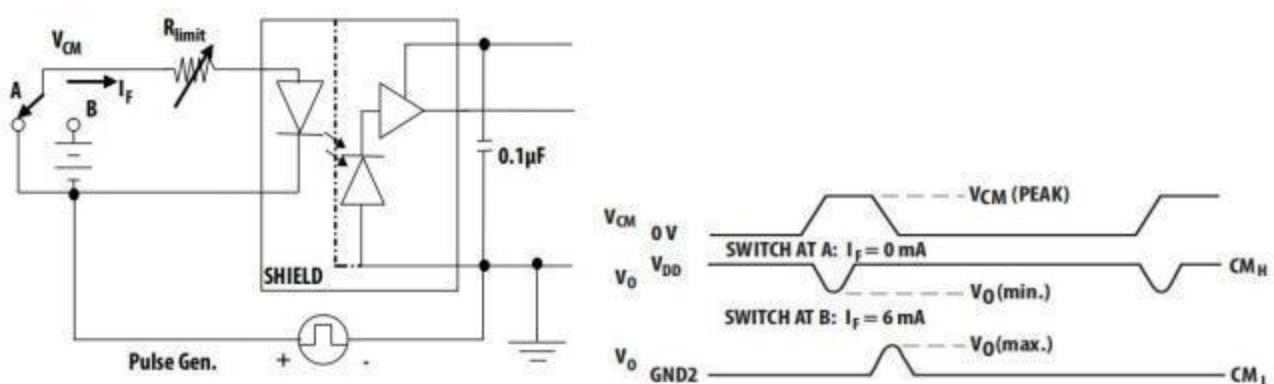
Fig.9 Propagation delay vs. Ambient temperature
(V_{DD}=3.3V,C_{peak}=100pF,R_{limit}=250 Ω)



延迟时间测试电路 propagationDelayTimeTestcircuit

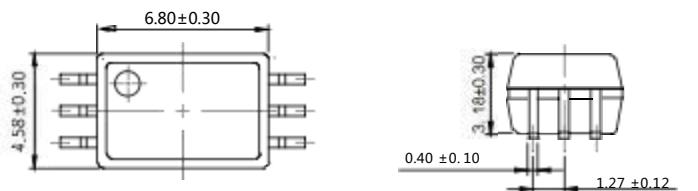


CMR测试电路 Test circuit for common Mode Transient Immunity

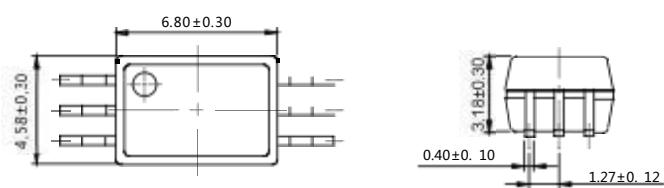


外形尺寸 。utlineDimensions

SOP6-W

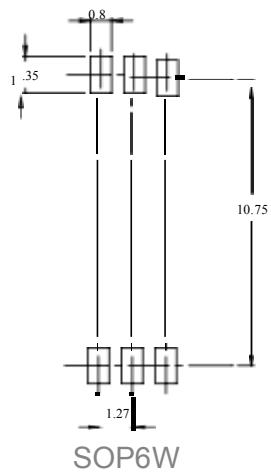


SOP6-P

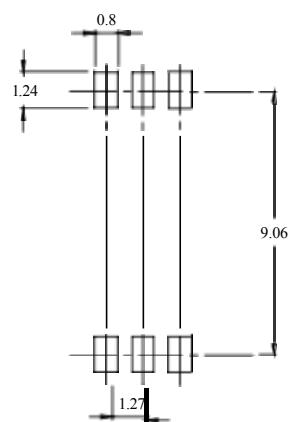


单位 Unit: mm

建议焊盘布局 Recommended pad Layout



SOP6W



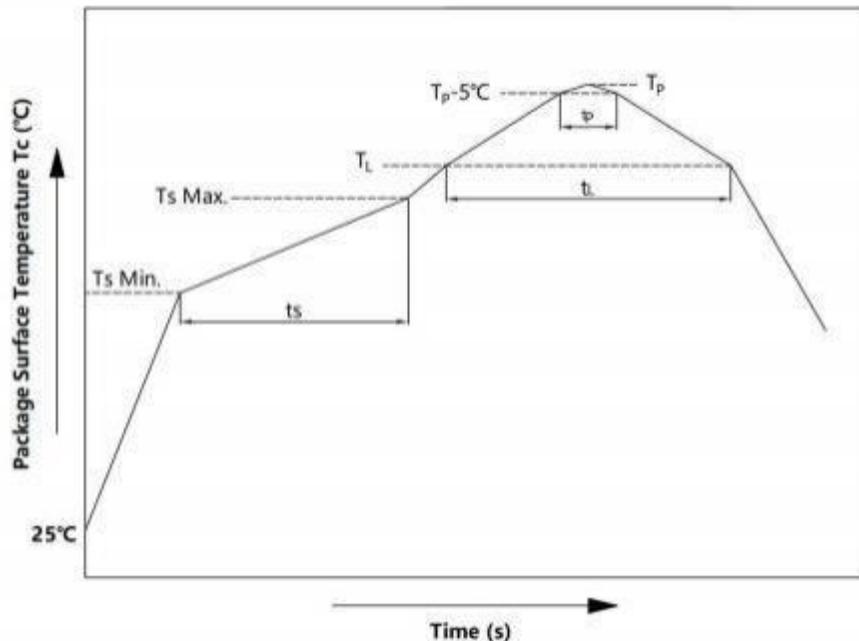
SOP6P

单位 Unit: mm

注：上图为产品正视图。

Note : The picture above is the front view of the product.

回流焊温度曲线图 solder Reflowprofile



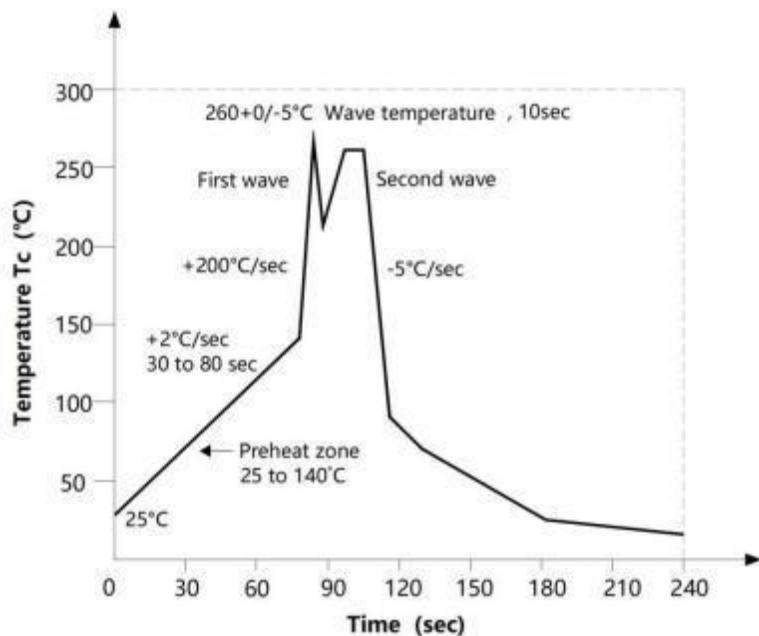
| 项目 Item | 符号 Symbol | 最小值 Min. | 最大值 Max. | 单位 Unit |
|---|--------------|-------------|-------------|-----------------------------|
| 预热温度 Preheat Temperature | T_s | 150 | 200 | $^{\circ}\text{C}$ |
| 预热时间 Preheat Time | t_s | 60 | 120 | s |
| 升温速率 Ramp-Up Rate (T_L to T_p) | - | - | 3 | $^{\circ}\text{C}/\text{s}$ |
| 液相线温度 Liquidus Temperature | T_L | 217 | | $^{\circ}\text{C}$ |
| 时间高于 T_L Time Above T_L | t_L | 60 | 150 | s |
| 峰值温度 Peak Temperature | T_p | - | 260 | $^{\circ}\text{C}$ |
| T_c 在(T_p -5)和 T_p 之间的时间 Time During Which T_c Is Between (T_p -5) and T_p | t_p | - | 30 | s |
| 降温速率 Ramp-down Rate(T_p to T_L) | - | - | 6 | $^{\circ}\text{C}/\text{s}$ |

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 wavesoldering profile



手工烙铁焊接 solderingwith handsolderingiron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间≤3s。
Hand soldering iron requirements : Temperature : $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

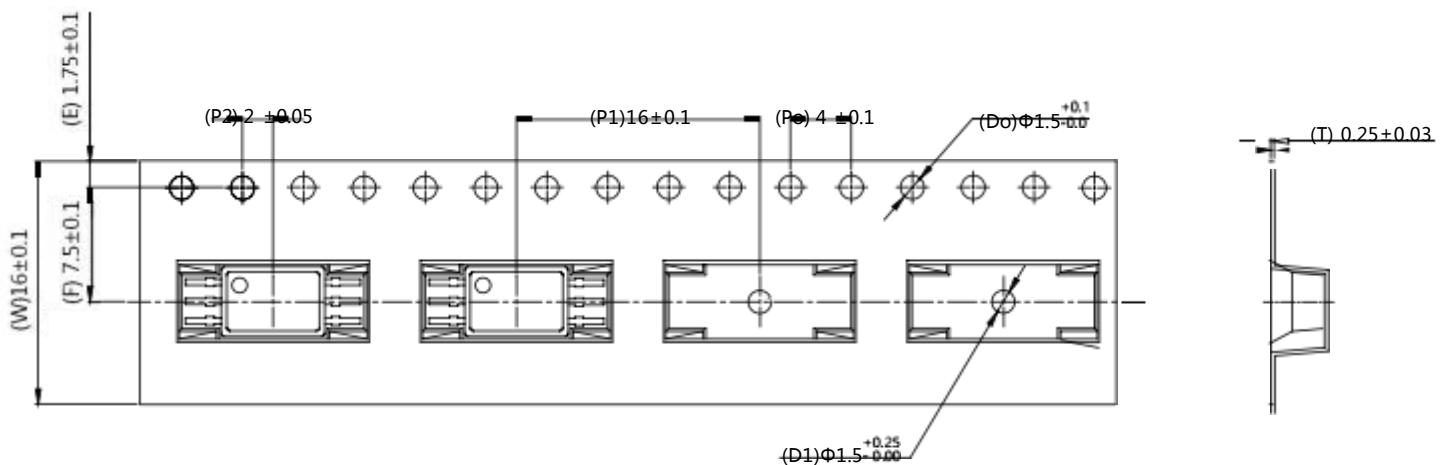
包装 packing

■ 汇总表summarytable

| 封装形式 | 包装方式 | 盘数量 | 盒数量 | 箱数量 | 静电袋规格 | 盒规格 | 箱(双瓦楞)规格 | 备注 |
|--------------|-------------------|-------------------|------------------|---------------------|------------------------------|-------------------|----------------------|-----------------------|
| SOP6 | 卷盘 (Φ330mm蓝盘) | 1千只/盘 | 2 盒/盒 | 10 盒/箱 | 450*390*0.1mm | 340*60*340mm | 620*360*365mm | 首尾端空至少200mm |
| Package Type | Packing Form | Quantity per Reel | Quantity per Box | Quantity per Carton | Antistatic Bag Specification | Box Specification | Carton Specification | Note |
| SOP6 | Reel(Φ330mm Blue) | 1k pcs/reel | 2Reel/box | 10box/ctn | 450*390*0.1mm | 340*60*340mm | 620*360*365mm | Guard band 200mm min. |

■ 编带包装Tape&Reel

- 1) 每卷数量 : 1000 只。
Qty/reel : 1000 pcs.
- 2) 每箱数量 : 20000 只。
Qty/ctn : 20000 pcs.
- 3) 内包装 : 每卷盘 1000 只。
Inner packing : 1000pcs/reel.
- 4) 示意图 Schematic :



单位 Unit : mm

注意 Attention

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